

IN THE CLAIMS:

1. to 9. (Canceled)

10. (Currently amended) An organic electroluminescence element comprising organic layers formed by ~~the method according to claim 2~~ depositing two or more organic materials by vacuum evaporation, comprising,

depositing each material under such control that an ni value of each organic material is $k \pm 0.5$ wherein k is a constant from 2 to 5,

when a relationship between a deposition position and a film thickness of a material i on the substrate is approximated by the following equation (1):

$$D_i/D_{0i} \propto (L_0/L_i)^3 \cos^{n_i} \theta_i \quad (1)$$

wherein L_0 is a distance from an evaporation source to a plane of the substrate in a perpendicular direction, D_{0i} is a film thickness of the material i at an intersection point of a perpendicular line from the evaporation source to the plane of the substrate, and D_i is a film thickness of the material i at a position on the substrate that is apart from the evaporation source by a distance L_i in a direction of an angle θ_i against the perpendicular line.

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11. (Currently amended) The organic electroluminescence element comprising a luminous layer formed by ~~the method according to claim 9~~ depositing a host material and a dopant material of a luminous layer of an organic electroluminescence element by vacuum evaporation, comprising,

co-depositing each material under such control that an ni value of each material is $k \pm 0.5$ wherein k is a constant from 2 to 5,

when a relationship between a deposition position and a film thickness of a material i on the substrate is approximated by the following equation (1):

$$\underline{D_i/D_{0i} \propto (L_0/L_i)^3 \cos^{n_i} \theta_i} \quad (1)$$

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wherein L_0 is a distance from an evaporation source to a plane of the substrate in a perpendicular direction, D_{0i} is a film thickness of the material i at an intersection point of a perpendicular line from the evaporation source to the plane of the substrate, and D_i is a film thickness of the material i at a position on the substrate that is apart from the evaporation source by a distance L_i in a direction of an angle θ_i against the perpendicular line.

12. (Currently amended) The organic electroluminescence element according to claim 10 ~~or 11~~, wherein a variation of an X coordinate of CIE luminescence chromaticity is 0.005/250 mm or less and a variation of a Y coordinate thereof is 0.02/250 mm or less.

13. (Currently amended) The organic electroluminescence element according to ~~any one of~~ claim 10 ~~to 12~~, wherein a variation of electric power conversion efficiency is 15%/250 mm or less.

14. (New) The organic electroluminescence element according to claim 11, wherein a variation of an X coordinate of CIE luminescence chromaticity is 0.005/250 mm or less and a variation of a Y coordinate thereof is 0.02/250 mm or less.

15. (New) The organic electroluminescence element according to claim 11, wherein a variation of electric power conversion efficiency is 15%/250 mm or less.

16. (New) The organic electroluminescence element according to claim 12, wherein a variation of electric power conversion efficiency is 15%/250 mm or less.